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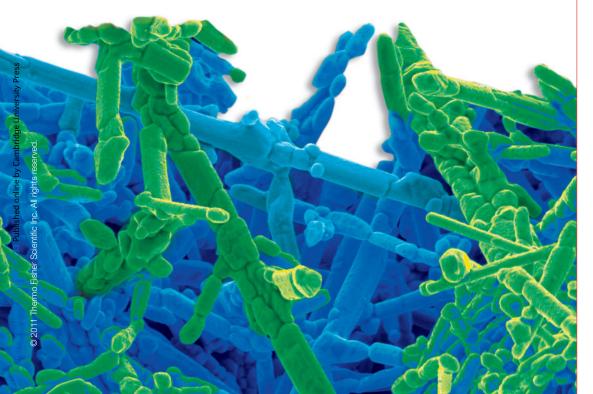


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Cover: Crystal structure of a typical skutterudite material CoSb₃. Transition metal atoms, Co, occupy 8*c* sites and pnicogen atoms, Sb, occupy 24*g* sites. Guest atom / could be filled into the voids at 2*a* sites. [X. Shi, S. Bai, L. Xi, J. Yang, W. Zhang, L. Chen, and J. Yang: Realization of high thermoelectric performance in n-type partially filled skutterudites. p. 1745.]

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